

## **isc Silicon NPN Power Transistor**

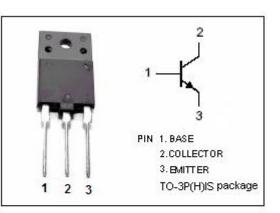
# 2SD1431

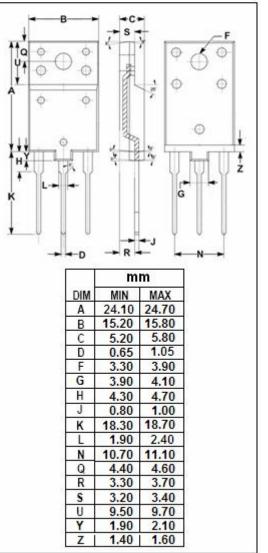
#### DESCRIPTION

- High Speed
- t<sub>f</sub>= 1.0 us(MIN) @ I<sub>C</sub>= 4A , I<sub>B(end)</sub>= 0.8A
- High Voltage V<sub>CBO</sub>=1300V
- Low Saturation Voltage V<sub>CE(sat)</sub><5.0V@ I<sub>C</sub> = 4A; I<sub>B</sub> = 0.8A
- · Minimum Lot-to-Lot variations for robust device performance and reliable operation

#### **APPLICATIONS**

· Designed for color TV horizontal output applications





## ABSOLUTE MAXIMUM RATINGS (Ta=25℃)

SYMBOL	PARAMETER	VALUE	UNIT
V <sub>CBO</sub>	Collector-Base Voltage	1300	V
Vceo	Collector-Emitter Voltage	600	V
V <sub>EBO</sub>	Emitter-Base Voltage	5	V
Ic	Collector Current-Continuous	5	A
lE	Emitter Current	5	А
Pc	Collector Power Dissipation @T <sub>c</sub> =25°C	80	W
Tj	Junction Temperature	150	°C
T <sub>stg</sub>	Storage Temperature Range	-55~150	°C



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### **ELECTRICAL CHARACTERISTICS**

#### $T_c=25^{\circ}C$ unless otherwise specified

PARAMETER	CONDITIONS	MIN	TYP.	MAX	UNIT
Collector-Emitter Saturation Voltage	I <sub>C</sub> = 4A; I <sub>B</sub> = 0.8A			5.0	V
Base-Emitter Saturation Voltage	I <sub>C</sub> = 4A; I <sub>B</sub> = 0.8A			1.5	V
Collector Cutoff Current	V <sub>CB</sub> = 500V; I <sub>E</sub> =0			10	μA
Emitter Cutoff Current	V <sub>EB</sub> = 5V; I <sub>C</sub> = 0			1.0	mA
DC Current Gain	I <sub>C</sub> = 1A; V <sub>CE</sub> = 5V	8	20		
Output Capacitance	I <sub>E</sub> = 0 ; V <sub>CB</sub> = 10V;f <sub>test</sub> = 1MHz		165		pF
	Collector-Emitter Saturation Voltage Base-Emitter Saturation Voltage Collector Cutoff Current Emitter Cutoff Current DC Current Gain	Collector-Emitter Saturation Voltage $I_C = 4A; I_B = 0.8A$ Base-Emitter Saturation Voltage $I_C = 4A; I_B = 0.8A$ Collector Cutoff Current $V_{CB} = 500V; I_E = 0$ Emitter Cutoff Current $V_{EB} = 5V; I_C = 0$ DC Current Gain $I_C = 1A; V_{CE} = 5V$	Collector-Emitter Saturation Voltage $I_C = 4A; I_B = 0.8A$ Base-Emitter Saturation Voltage $I_C = 4A; I_B = 0.8A$ Collector Cutoff Current $V_{CB} = 500V; I_E = 0$ Emitter Cutoff Current $V_{EB} = 5V; I_C = 0$ DC Current Gain $I_C = 1A; V_{CE} = 5V$	Collector-Emitter Saturation Voltage $I_C = 4A; I_B = 0.8A$ IBase-Emitter Saturation Voltage $I_C = 4A; I_B = 0.8A$ ICollector Cutoff Current $V_{CB} = 500V; I_E = 0$ IEmitter Cutoff Current $V_{EB} = 5V; I_C = 0$ IDC Current Gain $I_C = 1A; V_{CE} = 5V$ 820	Collector-Emitter Saturation Voltage $I_C = 4A; I_B = 0.8A$ 5.0Base-Emitter Saturation Voltage $I_C = 4A; I_B = 0.8A$ 1.5Collector Cutoff Current $V_{CB} = 500V; I_E = 0$ 10Emitter Cutoff Current $V_{EB} = 5V; I_C = 0$ 1.0DC Current Gain $I_C = 1A; V_{CE} = 5V$ 820

Switching times

tr	Fall Time				I <sub>C</sub> = 4A , I <sub>B(end)</sub> = 0.8A;		1.0	μ <b>S</b>
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